

### **Buck LED Driver**

# **Buck LED Driver for Automotive Suitable for Matrix LED Control**

### **BD18395EFV-M**

#### **General Description**

BD18395EFV-M is a Buck LED driver suitable for matrix LED control. It has a wide input voltage range from 4.5 V to 70 V with a possible average output current of 2.0 A max. A shutdown function reduces power consumption. The LED current can be set by an external current setting resistor, and it operates by peak current detection OFF TIME control. The device includes self-protection features such as UVLO, overcurrent protection, LED open detection, low output voltage detection, status good output and a thermal shutdown function.

The device is suitable for matrix control of LEDs.

#### **Features**

- AEC-Q100 Qualified<sup>(Note 1)</sup>
- Functional Safety Supportive Automotive Products
- Peak Current Detection OFF TIME Control System
- For Use with Matrix LED Control (High-speed Response Current Control)
- High-side LED Current Detection
- LED Voltage Maximum 60 V
- 
- Shutdown for Low Power Consumption<br>■ Control Loop Compensating Circuit is n ■ Control Loop Compensating Circuit is not needed<br>■ Normal State Flag Qutput (Status Good Signal)
- Normal State Flag Output (Status Good Signal)<br>■ Various Protection Functions
- **Various Protection Functions** *(Note 1)* Grade 1

#### **Applications**

■ Automotive Exterior Lamps

(Rear, Turn, DRL/Position, Fog, Dynamic Indicator, High/Low Beam, AFS Head Lamp, ADB Head Lamp etc.)

#### **Typical Application Circuit**

#### **Key Specifications**



**Package W (Typ) x D (Typ) x H (Max)** 6.5 mm  $x$  6.4 mm  $x$  1.0 mm



HTSSOP-B20



〇Product structure : Silicon integrated circuit 〇This product has no designed protection against radioactive rays

### **Pin Configuration**



### **Pin Description**



*(Note 1)* Leave this pin unconnected.

### **Block Diagram**



### **Description of Blocks**

#### **1 Control Method (OFF TIME Control)**

This product uses the OFF TIME control method for LED current control.

OFF TIME control consists of a comparator that detects the peak current of the LED and an OFF TIME generation circuit that generates a set signal in a time according to the output voltage.

First turn on the high side FET and let the current flow through the inductor. Current flowing through the inductor flows directly to the LED. The current flowing through the inductor is monitored by the voltage generated between the peak current detection resistors RSE, and when the set peak current is detected, the high side FET is turned off. After that, when the OFF TIME set inside the circuit elapses according to the Vf voltage of the generated LED, the high side FET is turned on again. By repeating this, LED current is controlled.

One characteristic of the OFF TIME control method is that it can reduce the output capacitor  $C_{\text{OUT}}$ . If the output capacitor is increased, the charge of the output capacitor flows to the LED as the rush current when reducing the number of LED lamps by matrix control, so it may cause flickering of the LED and breakdown beyond the rating. Also, when switching the number of LED lights, delay in output responsiveness due to LC filter made up of inductor and capacitor occurs. For this reason, it is necessary to minimize the output capacitor during matrix control.



Figure 1. OFF TIME Control Method

#### **Description of Blocks – continued**

#### **2 Reference Voltage VREG (5 V Output)**

The VREG voltage 5.0 V (Typ) is generated from the VB pin voltage and VREF block. This voltage is used as the internal power supply of the IC and the FET drive. It also supplies current to the SG pin and the LVD pin connected resistor. The total current supplied to the resistor must be 10 mA or less. Connect C<sub>VREG</sub> = 2.2 µF as feedback compensation capacitor to the VREG pin. Place ceramic capacitor close to the IC to minimize trace length to the VREG pin also to the IC ground. Do not use the VREG as a power supply other than this IC.

When the EN pin voltage exceeds the threshold voltage V<sub>ENH</sub>, the reference voltage generation circuit starts operating. When the EN pin voltage falls below the threshold voltage VENL, all internal circuits including the reference voltage generation circuit stop operating and the circuit current becomes 0 µA (Typ).

#### **3 SG (Status Good Signal)**

The SG pin has an open drain output and requires an external pull-up to the power supply for use. When the LED driver is activated and the current control circuit detects the peak current three times, the SG pin is Hiz controlled. In addition, when a failure is detected (UVLO, TSD, OCP, LED OPEN), the SG pin is controlled low. (See 7. Fault Detection / Protection Functions.) This SG signal can be used as an enable signal for the Matrix SW driver. (For applications using Matrix SW, refer to the application circuit example.)



Figure 2. Explanation of SG Signal Operation (When Switching the EN Pin Low/High)

#### **4 Average LED Current Control**

4.1 SECOMP (Peak current detection)

The voltage between the SNSP and SNSN pins is used to detect the peak current flowing through the inductor. The detection resistor R<sub>SE</sub> is connected between the SNSP pin and the SNSN pin, and the voltage between the pins is adjusted to  $V_{\text{SNS}}$  = 200 mV (Typ). Therefore, the LED peak current  $I_{\text{LED MAX}}$  can be set by the following formula.

$$
I_{LED\_MAX} = \frac{0.2}{R_{SE}} \quad [A]
$$

 $R_{SE}$ : Peak current detection resistance

- 4.2 OFF TIME Control (OFF TIME Generation Circuit)
	- OFF TIME block generates the set signal of the time to depend on the VLED pin voltage V<sub>VLED</sub>. When peak current is detected, the high side FET is off, and the OFF TIME count starts. When OFF TIME passes, the set signal is output, and the high side FET is turned on. Since the OFF TIME is generated according to the VLED pin voltage, it varies under the control of the Matrix SW controller, but the ripple of the LED current is controlled to be constant. The OFF TIME can be changed by the external resistor  $R_{TOFF}$  connected to the TOFF pin, and the switching frequency can be adjusted. The maximum time is set in OFF TIME (MAX OFF TIME Detection), and the set signal is automatically output when counting 80  $\mu$ s or more (same time as t<sub>OPEN</sub>).

4.2 OFF TIME Control (OFF TIME Generation Circuit) – continued The OFF TIME  $(t_{OFF})$  is set using the formula shown below.

$$
t_{OFF} = 1.05 \times 10^{-9} \times \frac{R_{TOFF}}{V_{VLED}}
$$
 [s]

 $R_{TOFF}$ : External resistance value connected to the TOFF pin  $V_{VLED}$ : LED Vf voltage (= VLED pin voltage)

tor F affects the switching frequency fsw. fsw can be determined according to the formula below.

$$
f_{SW} = \frac{V_{SNSP} - V_{VLED}}{V_{SNSP} + V_{SBD}} \times \frac{1}{t_{OFF}} \quad \text{[Hz]}
$$

 $R_{TOFF}$ : External resistance value connected to the TOFF pin

 $V_{VLED}$  : LED Vf voltage (= VLED pin voltage)

 $V_{SNSP}$  : SNSP pin voltage

 $V_{SBD}$  : Schottky barrier diode forward voltage

This formula shows parabolic characteristics and the switching frequency becomes maximum when  $V_{\text{VLED}} = V_{\text{SNSP}}/$ 2.

The maximum value of the switching frequency fsw MAX is calculated by the formula below.

$$
f_{SW\_MAX} = \frac{v_{SNSP}^2}{2 \times (v_{SNSP} + v_{SBD}) \times 2.10 \times 10^{-9} \times R_{TOFF}} \quad \text{[Hz]}
$$

 $R_{TOFF}$ : External resistance value connected to the TOFF pin

 $V_{SNSP}$  : SNSP pin voltage

 $V_{SBD}$  : Schottky barrier diode forward voltage

Due to the circuit delay, fsw MAX will be lower than this calculation suggests.



 $(V_{SNSP} = 30 V, V_{SBD} = 0.7 V, R_{TOFF} = 10 kΩ, 20 kΩ, 47 kΩ)$ 

Using the above graph, determine the maximum switching frequency fsw MAX and RTOFF for a given VSNSP.

$$
R_{TOFF} = \frac{V_{SNSP}^2}{2 \times (V_{SNSP} + V_{SBD}) \times 2.10 \times 10^{-9} \times f_{SW\_MAX}} \quad [\Omega]
$$

 $V_{SNSP}$  : SNSP pin voltage

 $V_{SBD}$  : Schottky barrier diode forward voltage

4.3 DRV Logic (Output control logic)

The high side FET is controlled according to the output signal (reset) of the SECOMP circuit and the output signal (set) of the OFF TIME circuit. The switching frequency can be adjusted.

### **Description of Blocks – continued**

### **5 Dimming Function**

To adjust the LED current, the PWM dimming function and analog dimming function is integrated in this IC.

5.1 PWM Control (PWM Dimming) The LED current ON/OFF is controlled by inputting a PWM signal to the PWM pin. It is ON control when PWM = High and OFF control when PWM = Low. No additional FET are required for PWM control.



Figure 4. PWM Dimming Operation

5.2 DC Dimming (Analog Dimming)

If a derating in the current is desired, due to LED temperature, the analog dimming function can be used. The LED peak current is adjusted according to the voltage applied to the DCDIM pin. If the DCDIM voltage V<sub>DCDIM</sub> is above 1.0 V (Typ), the peak detection voltage Vs<sub>NS</sub> is 200 mV (Typ). If a lower voltage is applied, the peak detection voltage will be reduced, as shown in the diagram below. If the analog dimming function is not used, connect the DCDIM pin to the VREG pin with 10 k $\Omega$  or more.



Figure 5. Analog Dimming

### **Description of Blocks – continued**

#### **6 Zero LED Operation**

When driving Matrix SW such as dynamic indicator, all Matrix SW may be turned on and LED may be 0. At this time, the current supplied from the LED driver does not flow to the LED but flows to the Matrix SW, and the switching operation continues.



Figure 6. Current Path at Zero LED

- 6.1 Low Voltage Detection (LED Anode Low Voltage Detection Function)
	- BD18395EFV-M has the LVD (Low Voltage Detection) function in order to detect if the voltage of the VLED pin which connects to the LED anode side goes down. When the voltage of the VLED pin becomes lower than the set voltage when the SFON pin voltage V<sub>SFON</sub> > 2.4 V, it acts as ground fault detection (SCP) on the LED anode side and outputs the SG pin Low to notify abnormality. When the SFON pin voltage V<sub>SFON</sub> < 0.6 V, the current drive operation is continued while keeping the SG pin Hiz output. The detection voltage of LVD is set by the voltage value externally input to the LVD pin. Connect external resistors RLVDH, RLVDL between the VREG pin and the GND pin, and set arbitrarily according to Vf of LED.



Figure 7. How to Set the LVD Voltage

The low voltage detection voltage  $V_{LVD}$  is calculated by the following formula. The minimum VLED pin voltage depends upon the number of LEDs and their Vf. The LVD detection voltage must be between 1.5 V and 2.75 V.

$$
V_{LVD} = V_{REG} \times \frac{R_{LVDL}}{R_{LVDH} + R_{LVDL}}
$$
 [V]

 $V_{REG}$ : VREG output voltage  $R_{LVDH}$ ,  $R_{LVDL}$ : LVD pin connection resistance

The low voltage detection voltage VLV<sub>D</sub> should be set lower than a single LED Vf. Therefore, consider the variation of LED Vf when setting the low voltage detection voltage. An example is shown below.

- 6.1. Low Voltage Detection (LED Anode Low Voltage Detection Function) continued
	- 6.1.1 The Low Voltage Detection Voltage Setting Example (When Using the Matrix SW)



Min voltage value of the LED anode side, in case of a single LED

$$
V_{LED} = V_f + (I_{LED\_AVE} - \Delta I_{LED}) \times R_{ON\_MIN} \times (N - 1)
$$
 [V]  
= 1.6 V + (1.0 A - 0.1 A) x 0.12  $\Omega$  x (8-1) = 2.356 V

Taking the dispersion (±5 %) of VREG into consideration, the low voltage detection voltage is set to 2.0 V. Therefore, determine the resistance to be connected the LVD pin: RLVDH = 30 kΩ, RLVDL = 20 kΩ.

#### **Description of Blocks – continued**

#### **7 Malfunction Detection / Protective Functions**



- 7.1 Under Voltage Locked Out (UVLO) UVLO is a protection circuit that prevents IC malfunction at power-on or power-off. This IC is equipped with 3 UVLO circuits: UVLO VB for the VB voltage, UVLO VREG for the VREG voltage and UVLO SNSP for the SNSP voltage. When UVLO is detected, the switching operation stop, and the high side FET is turned off. Also, during UVLO detection, the SG pin is set to Low output to notify the outside of an abnormality.
- 7.2 Thermal Protection Circuit (TSD Thermal Shutdown) TSD is a protection circuit to prevent IC destruction due to abnormal heat generation. The TSD stops switching at 175 ° C (Typ), recovers at 150 ° C (Typ), and starts switching operation again. Also, during TSD detection, the SG pin is set to Low output to notify the outside of the abnormality.
- 7.3 Overcurrent Protection Circuit (OCP) By detecting the current flowing between the VPOW pin and the SW pin and prevents destruction due to an excess current higher than the tolerance of the high side FET, inductor or LED. When the OCP operates, it stops the step-down switching operation and the high side FET turned off. Hence the output of the SW pin will be Low. The step-down switching operation starts again when the OFF TIME, which depends on the VLED pin voltage, has passed, after the output of the SW pin has become Low.

#### 7.3 Overcurrent Protection Circuit (OCP) – continued

If OCP is detected even once, the SG pin is set to Low output to notify the outside of the abnormality. If OCP is detected twice when the SG pin is low output, it will be in a hiccup operation, and after 10 ms (Typ) of OCP detection has elapsed, the step-down switching operation will start again. If the peak current detection comparator operates three times in succession without detecting OCP, the SG pin returns from the Low state to the Hiz state.



Figure 8. OCP Detection Operation

7.4 LED Open Detection (LED OPEN)

An abnormality is detected when an open failure occurs in the LED or a connector opening to the LED board occurs. Since no current flows through the current detection resistor when the LED is open, no peak current detection signal is generated, and the high side FET is kept on. When 80 μs or more of the high side FET is turned on, it recognizes the LED open state and outputs the reset signal to turn off the high side FET. Also, output the SG pin Low to notify abnormality to the outside.



Figure 9. LED OPEN Detection Operation

#### **7 Malfunction Detection / Protective Functions – continued**

7.5 TOFF Pin Short Detection Function

When the TOFF pin short-circuited with GND or when external resistor R $_{\rm TOFF}$  short-circuited, the TOFF pin short detection function detects abnormality. When the TOFF pin short detection function detects abnormality, the high side FET is turned off, and the SG pin outputs Low.

### **Absolute Maximum Ratings (Ta = 25 °C)**



Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit<br>between pins and the internal circuitry. Therefore, it is important *operated over the absolute maximum ratings.*

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the<br>properties of the chip. In case of exceeding this absolute maximum *increasing board size and copper area so as not to exceed the maximum junction temperature rating.*

#### **Thermal Resistance** *(Note 1)*



*(Note 5)* This thermal via connects with the copper pattern of all layers.

### **Recommended Operating Conditions**



*(Note 1)* ASO should not be exceeded.

*(Note 2)* At start-up time, apply the voltage 5 V or more once. The value is the voltage range after the temporary rise to 5 V or more.

### **Recommended Setting Parts Range**



*(Note 3)* Capacitor capacitance should be set considering temperature characteristics, DC bias characteristics, etc.

### **Electrical Characteristics**

### (Unless otherwise specified  $V_B$  = 13 V,  $V_{SNSP}$  = 13 V,  $V_{EN}$  = 5 V, Tj = 25 °C)



## **Electrical Characteristics - continued**

### **(Unless otherwise specified VB = 13 V, VSNSP = 13 V, VEN = 5 V, Tj = 25 °C)**



### **Typical Performance Curves (Reference Data)**



Figure 10. VB Standby Current vs VB Pin Voltage Figure 11. VB Circuit Current vs VB Pin Voltage



Figure 12. SNSP Standby Current vs SNSP Pin Voltage Figure 13. SNSP Circuit Current vs SNSP Pin Voltage







Figure 14. VB UVLO Detection/Release Voltage vs Ambient Temperature







-50 -25 0 25 50 75 100 125 150

Ambient Temperature [℃]

4.75











Figure 21. MOS FET ON Resistance between the SW and GND Pins vs Ambient Temperature  $(I<sub>SW</sub> = 10 mA)$ 



Figure 22. LED Peak Detection Voltage vs Ambient **Temperature** 



Figure 24. Overcurrent Detection vs Ambient Temperature





Figure 25. Efficiency vs SNSP Pin Voltage ( $V_B$  = 13 V, I<sub>LED</sub> = 1 A,  $R_{TOFF}$  = 20 k $\Omega$ , L = 100 µH)



Figure 26. LED Current vs SNSP Pin Voltage  $(V_B = 13$  V, R<sub>TOFF</sub> = 20 kΩ, L = 100 μH)



Figure 28. EN Start-up  $(V_B = 13 V, V_{SNSP} = 13 V, L = 47 uH, L_{ED} = 1 A)$ 





Tek  $\boxed{-}$   $\boxed{\mathbf{x}}$ 

### **Typical Performance Curves (Reference Data) - continued**



Figure 30. PWM Dimming (V<sub>B</sub> = 13 V,  $V_{SNSP}$  = 13 V, L = 47  $\mu$ H, I<sub>LED</sub> = 1 A,  $PWM = 1$  kHz, Duty = 0.5 %)

Figure 29. PWM Dimming  $(V_B = 13 V, V_{SNSP} = 13 V, L = 47 \mu H, L_{LED} = 1 A,$  $PWM = 1$  kHz, Duty = 50 %)

### **Timing Chart**

### **1. Start-up Sequence Controlled EN**

(Start-up sequence of VB/SNSP is arbitrary)



Figure 31. Timing Chart (ON/OFF Control with the EN Pin)

#### **Timing Chart – continued**

### **2. Start-up Sequence for SNSP Rising 1 [EN Tied to VB]**

(VB Start-up **→** SNSP Start-up / SNSP Shutdown **→** VB Shutdown)



Figure 32. Timing Chart (VB Start-up  $\rightarrow$  SNSP Start-up)

#### **Timing Chart – continued**

**3. Start-up Sequence for SNSP Rising 2 [EN Tied to VB]** (SNSP Start-up **→** VB Start-up / VB Shutdown **→** SNSP Shutdown)



Figure 33. Timing Chart (SNSP Start-up → VB Start-up)

### **Application Examples**

**1 3 LEDs (White), ILED = 2 A Setting**



Figure 34.  $V_B$  = 13 V, ILED = 2 A, LED = 3 Series, Frequency = 210 kHz

#### **Recommended Parts List**



### **Application Examples - continued**

**2 8 LEDs (White), ILED = 1 A Setting**



Figure 35.  $V_{IN}$  = 48 V,  $V_B$  = 13 V,  $I_{LED}$  = 1 A, LED = 8 Series, Frequency = 250 kHz



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### **Application Examples - continued**

**3 16 LEDs (Yellow), ILED = 350 mA Setting**



Figure 36.  $V_{IN}$  = 60 V,  $V_B$  = 13 V,  $I_{LED}$  = 350 mA, LED = Yellow 16 Series, Frequency = 350 kHz



#### **Recommended Parts List**

#### **Application Examples - continued**

#### **4 8 LEDs (Yellow), ILED = 300 mA, with the Matrix SW Setting**



Figure 37. Use BD18395EFV-M and BD18362EFV-M *(Note 1)* 8 ch Dynamic Indicator  ${BDI8395EFV-M: V_{IN} = 24 V, V_B = 13 V, I_{LED} = 300 \text{ mA}, LED = Yellow 8 Series (18.4 V), Frequency = 310 kHz}$ {BD18362EFV-M: 8 ch Setting, The Sequential Lighting Phase Time tPS1 = 15 ms, The Sequential Lighting Start-up Delay Time  $t_{\text{DLY}}$  = 1.25 ms}

### **- Application of Dynamic Indicator (Use BD18395EFV-M and BD18362EFV-M** *(Note 1)***)**

The BD18395EFV-M has SG function (status good), and by using this function, it is easy to design the dynamic indicator application using BD18362EFV-M (8 ch Matrix SW).

· Connect the SG signal of BD18362EFV-M to the EN pin of BD18395EFV-M

· Connect the SG signal of BD18395EFV-M to the SETDLY pin of BD18362EFV-M

By starting the operation by connecting the above two points

Start operation

 $\rightarrow$  All the SW of BD18362EFV-M are ON (the SG pin of BD18362EFV-M = High).

 $\rightarrow$  The EN pin of BD18395EFV-M becomes High, so the driver operation starts.

 $\rightarrow$  Driver operation is normal, the SG pin of BD18395EFV-M = High.

 $\rightarrow$  The SETDLY pin of BD18362EFV-M becomes High, so sequential operation is started.

This prevents chattering at LED startup due to variation in startup time setting.

*(Note 1)* Please refer to datasheet for usage of BD18362EFV-M.

#### **4 8 LEDs (Yellow), ILED = 300 mA, with the Matrix SW Setting - continued**

#### **Recommended Parts List**



### **Selection of Parts Externally Connected**

Please follow the below procedure for selecting application parts.



### **Selection of Parts Externally Connected - continued**

#### **1. Confirm Usage Conditions**

Confirm the following usage conditions before proceeding with calculations.



#### **2. Selection of the Resistance RTOFF to Set Oscillating Frequency**

Calculate oscillating frequency from power supply voltage V<sub>SNSP</sub> and the VLED pin voltage V<sub>VLED</sub> Oscillating frequency can be adjusted by the external resistance  $R_{TOFF}$ . Oscillating frequency, fsw can be calculated by the following formula:

 $f_{SW} = \frac{V_{SNSP}-V_{VLED}}{V_{SNSP}+V_{SPD}}$  $\frac{V_{SNSP}-V_{VLED}}{V_{SNSP}+V_{SBD}} \times \frac{1}{t_{OR}}$  $\frac{1}{t_{OFF}} = \frac{V_{SNSP}-V_{VLED}}{V_{SNSP}+V_{SBD}}$  $\frac{V_{SNSP}-V_{VLED}}{V_{SNSP}+V_{SBD}} \times \frac{V_{VLED}}{1.05 \times 10^{-9} \times}$  $1.05\times10^{-9}\times R_{TOFF}$  [Hz]  $R_{TOFF}$  : External resistance value to connect at the TOFF pin<br>  $V_{VIED}$  : LED Vf voltage (= VLED pin voltage)  $V_{VLED}$  : LED Vf voltage (= VLED pin voltage)<br>  $V_{SNSP}$  : SNSP pin voltage  $V_{SNSP}$  : SNSP pin voltage<br>  $V_{SRD}$  : External Schottky : External Schottky barrier diode forward direction voltage

When used in combination with Matrix SW controller, while switching LEDs, the frequency becomes minimum with either the minimum number of LED lights (other than zero) or the maximum number of LED lights. Also, when  $V_{VLED} = V_{SNSP}/2$ , the oscillation frequency becomes maximum.

#### **3. Selection of the Inductor**

Calculate the desired LED current ripple  $I_{LED}$  RIPPLE by selecting an optimal inductor value.

Recommended output ripple current is within 5 % to 20 % of desired LED current.

Value of inductor can be calculated by substituting the values of R<sub>TOFF</sub> from step 2 above and desired LED current ripple, in the following formula:

$$
I_{LED\_RIPPLE} = \frac{V_{VLED} + V_{SBD}}{L} \times t_{OFF} = \frac{V_{VLED} + V_{SBD}}{L} \times 1.05 \times 10^{-9} \times \frac{R_{TOFF}}{V_{VLED}}
$$
 [A]

 $R_{TOFF}$  : External resistance value to connect at the TOFF pin<br>  $V_{VLED}$  : LED Vf voltage (= VLED pin voltage)  $V_{VLED}$  : LED Vf voltage (= VLED pin voltage)<br> $V_{SBD}$  : External Schottky barrier diode forwa  $V_{SBD}$ <br> $V_{SBD}$  : External Schottky barrier diode forward direction voltage : Inductor value

#### **4. Selection of the Peak Current Detection Resistance RSE**

Calculate the average LED current  $I_{LED, AVE}$  and select the value of the peak current detection resistor RsE. Calculate the LED average current based on the R<sub>TOFF</sub> and L values obtained in 2 and 3 above and calculate the peak current detection resistance value.

The average LED current ILED\_AVE is calculated by the following formula:

$$
I_{LED\_AVE} = \frac{0.2}{R_{SE}} - \frac{I_{LED\_RIPPLE}}{2}
$$
 [A]

 $R_{SE}$  : Peak current detection resistance<br>  $I_{LED \ RIPPLE}$  : LED ripple current : LED ripple current

### **Selection of Parts Externally Connected - continued**

#### **5. Calculate Power Consumption**

Calculate power consumption from input voltage, number of LEDs, LED average current and oscillating frequency. Use the following formulae to calculate IC power consumption:





#### **6. Setting the Low Voltage Detection**

If you have a situation where you are using the Matrix SW controller and all the switches are on and the LEDs are 0, you need to set the low voltage detection voltage VLVD to detect that the LEDs are 0. The low voltage detection voltage is set by the voltage value input from the outside to the LVD pin. Connect external resistors  $R_{LVDL}$  and  $R_{LVDL}$  between the VREG pin and the GND pin. Also, set the low voltage detection voltage to be in the range of 1.5 V to 2.75 V. It must be set lower than the Vf voltage when one LED is lit.

The low voltage detection voltage  $V_{LVD}$  is calculated by the following formula.

$$
V_{LVD} = V_{REG} \times \frac{R_{LVDL}}{R_{LVDH} + R_{LVDL}}
$$
 [V]

Figure 38. How to Set the Low Voltage Detection

### **Selection of Parts Externally Connected - continued**

#### **7. Selection of the Input Capacitor and the Output Capacitor**

A capacitor is required on the input side of switching type LED driver as peak current flows between input and output. Capacitor value of 4.7 μF or more with ESR of 100 mΩ or less, is recommended at the input. Capacitor beyond this range may cause excessive ripple on the input, causing malfunction of the IC.

#### **8. Selection of the Schottky Barrier Diode**

In the switching type Buck LED driver, when the High side FET is turned off, the current is supplied from the external Schottky barrier diode. Therefore, select a schottky barrier diode whose current capacity is sufficiently higher than the LED current. Also, if the Vf voltage of the diode is high, not only the power loss will increase, but also the SW pin voltage will become a negative voltage, which may cause the circuit inside the LSI to malfunction. Therefore, a diode with as low a Vf voltage as possible is recommended.

#### **9. Confirm Operation in Actual Application**

The characteristics will change depending on the LED current, input voltage, output voltage, inductor value, load capacity, switching frequency, mounting pattern, etc., so be sure to check with the actual application.

### **I/O Equivalence Circuit**



### **I/O Equivalence Circuit - continued**



#### **Operational Notes**

#### **1. Reverse Connection of Power Supply**

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

#### **2. Power Supply Lines**

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

#### **3. Ground Voltage**

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition. However, pins that drive inductive loads (e.g. motor driver outputs, DC-DC converter outputs) may inevitably go below ground due to back EMF or electromotive force. In such cases, the user should make sure that such voltages going below ground will not cause the IC and the system to malfunction by examining carefully all relevant factors and conditions such as motor characteristics, supply voltage, operating frequency and PCB wiring to name a few.

#### **4. Ground Wiring Pattern**

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

#### **5. Recommended Operating Conditions**

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

#### **6. Inrush Current**

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

#### **7. Testing on Application Boards**

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

#### **8. Inter-pin Short and Mounting Errors**

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

#### **9. Unused Input Pins**

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

#### **Operational Notes – continued**

#### **10. Regarding the Input Pin of the IC**

This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P-N junctions are formed at the intersection of the P layers with the N layers of other elements, creating a parasitic diode or transistor. For example (refer to figure below):

When GND > Pin A and GND > Pin B, the P-N junction operates as a parasitic diode. When GND > Pin B, the P-N junction operates as a parasitic transistor.

Parasitic diodes inevitably occur in the structure of the IC. The operation of parasitic diodes can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions that cause these diodes to operate, such as applying a voltage lower than the GND voltage to an input pin (and thus to the P substrate) should be avoided.



Example of Monolithic IC Structure

#### **11. Ceramic Capacitor**

When using a ceramic capacitor, determine a capacitance value considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

#### **12. Thermal Shutdown Circuit (TSD)**

This IC has a built-in thermal shutdown circuit that prevents heat damage to the IC. Normal operation should always be within the IC's maximum junction temperature rating. If however the rating is exceeded for a continued period, the junction temperature (Tj) will rise which will activate the TSD circuit that will turn OFF power output pins. When the Tj falls below the TSD threshold, the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

#### **13. Over Current Protection Circuit (OCP)**

This IC incorporates an integrated overcurrent protection circuit that is activated when the load is shorted. This protection circuit is effective in preventing damage due to sudden and unexpected incidents. However, the IC should not be used in applications characterized by continuous operation or transitioning of the protection circuit.

#### **14. Functional Safety**

"ISO 26262 Process Compliant to Support ASIL-\*"

A product that has been developed based on an ISO 26262 design process compliant to the ASIL level described in the datasheet.

"Safety Mechanism is Implemented to Support Functional Safety (ASIL-\*)"

A product that has implemented safety mechanism to meet ASIL level requirements described in the datasheet. "Functional Safety Supportive Automotive Products"

A product that has been developed for automotive use and is capable of supporting safety analysis with regard to the functional safety.

Note: "ASIL-\*" is stands for the ratings of "ASIL-A", "-B", "-C" or "-D" specified by each product's datasheet.

### **Ordering Information**



#### **Marking Diagram**



### **Physical Dimension and Packing Information**



#### < Tape and Reel Information >



### **Revision History**



# **Notice**

#### **Precaution on using ROHM Products**

1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment  $(Note 1)$ , aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.





2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:

[a] Installation of protection circuits or other protective devices to improve system safety

[b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure

- 3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
	- [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
	- [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
	- [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
	- [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
	- [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
	- [f] Sealing or coating our Products with resin or other coating materials
	- [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
	- [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### **Precaution for Mounting / Circuit board design**

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

#### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
	- [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
	- [b] the temperature or humidity exceeds those recommended by ROHM
	- [c] the Products are exposed to direct sunshine or condensation
	- [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

#### **Precaution for Disposition**

When disposing Products please dispose them properly using an authorized industry waste company.

#### **Precaution for Foreign Exchange and Foreign Trade act**

Since concerned goods might be fallen under listed items of export control prescribed by Foreign exchange and Foreign trade act, please consult with ROHM in case of export.

#### **Precaution Regarding Intellectual Property Rights**

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